				Complete if Known		
				Application Number	10 1765 804	
INFORMATION DISCLOSURE				Filing Date	1-27-04	
STATEMENT BY APPLICANT (use as many sheets as necessary)				First Named Inventor	Paul A. Ingersoll	
				Group Art Unit	2829	
				Examiner Name	B.KEBEDE	
Sheet	11	of	1	Attorney Docket Number	SC13113TP	

			U. S. PATENT DOCU	MENTS	
Examiner Initials*	Cite No. 1	Document Number Number -Kind Code² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
Box	AA	US -6,611,019 B2	08-26-2003	RUDECK	
BIL	AB	US -6,574,144 B2	06-03-2003	FORBES	
BN	AC	US -6,413,819 B1	07-02-2002	ZAFAR	
BR	AD	US -3,878,549	04-15-1975	YAMAZAKI	
		US-			
		US-			
		US-			
		US-		1	
	1	US·			
		US			
		US-			

		FOREIGN PA	ATENT DOCUMENT	S	· · · · · · · · · · · · · · · · · · ·		
Examine	Cite No. 1	Foreign Patent Document Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>2</sup> (if	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or	T 6	
Initials*		known)	WWFDD-1111	Applicant of Cited Document	Relevant Figures Appear		
	<u> </u>						
		NON DATENT LE	TERATURE DOCUM	ENTE			
Examiner	Cite No.				item (heek manning inums)	172	
Initials*	Gile No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journ serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.					
Bu	AE	WATANABE et al., "An Advanced Technique for Fabricating Hemispherical-Grained (HSG) Silicon Storage Electrodes," IEEE TRANSACTIONS ON ELECTRON DEVICES, VOL. 42, NO. 2, FEBRUARY 1995, pp. 295-300.					
Von	AF	DE BLAUWE et al., "A Novel, Aeroso Applications," IEEE, pp. 29.7.1 – 29.7		ting-Gate Device for Non-V	olatile Memory		

Examiner	0		Date	
Signature	Brook	Resede	Considered	4/17/2005

EXAMINER: Initial If reference considered, whether or not citation is in conformance with MPEP 609. Oraw line through citation, if not in conformance and not considered. Include copy of this form with

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> See Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WiPO Standard ST.3). <sup>4</sup> For Japanese patent documents the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>3</sup> Kind of document by the appropriate symbols as indicated on the document under WiPO Standard ST. 16 if possible. <sup>8</sup> Applicant is to place a check mark here if English Language Translation is attached.

If you need assistance in completing the form, call 1-800-PTO-9199 (1-800-786-9199) and select option 2.